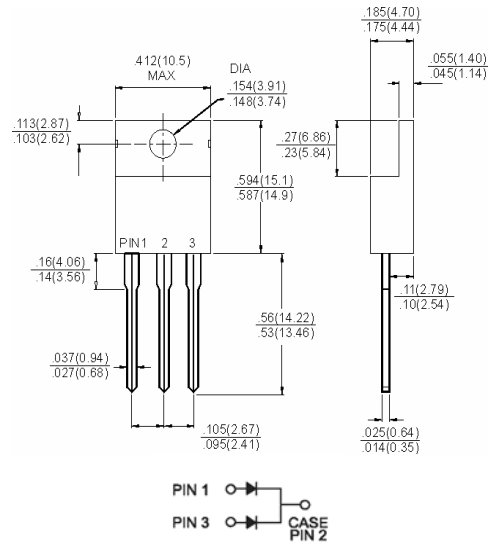




Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed:
260°C/10 seconds, 0.25" (6.35mm) from case



Mechanical Data

- Cases: JEDEC TO-220AB molded plastic
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. - lbs. max
- Weight: 0.08 ounce, 2.24 grams

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 2035 CT	MBR 2045 CT	MBR 2050 CT	MBR 2060 CT	MBR 2090 CT	MBR 20100 CT	MBR 20150 CT	MBR 20200 CT	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	90	100	150	200	V
Maximum RMS Voltage	V _{RMS}	24	31	35	42	63	70	105	140	V
Maximum DC Blocking Voltage	V _{DC}	35	45	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current at T _C =135°C	I _(AV)	20								A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at T _C =135°C	I _{FRM}	20								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150								A
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1.0		0.5						A
Maximum Instantaneous Forward Voltage at (Note 2) IF=10A, TC=25°C IF=10A, TC=125°C IF=20A, TC=25°C IF=20A, TC=125°C	V _F	— 0.57 0.84 0.72		0.80 0.70 0.95 0.85		0.85 0.75 0.95 0.85		0.99 0.87 1.23 1.10		V
Maximum Instantaneous Reverse Current @ T _C =25°C at Rated DC Blocking Voltage @ T _C =125°C	I _R	0.1 15 10 5.0 0.15								mA mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000								V/uS
Typical Junction Capacitance	C _j	400		320						pF
Typical Thermal Resistance Per Leg (Note 3)	R _{θJC}	1.0				2.0				°C/W
Operating Junction Temperature Range	T _J	-65 to +150								°C
Storage Temperature Range	T _{STG}	-65 to +175								°C

Notes: 1. 2.0 μs Pulse Width, f=1.0 KHz
2. Pulse Test: 300 μs Pulse Width, 1% Duty Cycle
3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate.

RATINGS AND CHARACTERISTIC CURVES (MBR2035CT THRU MBR20200CT)

FIG.1- FORWARD CURRENT DERATING CURVE

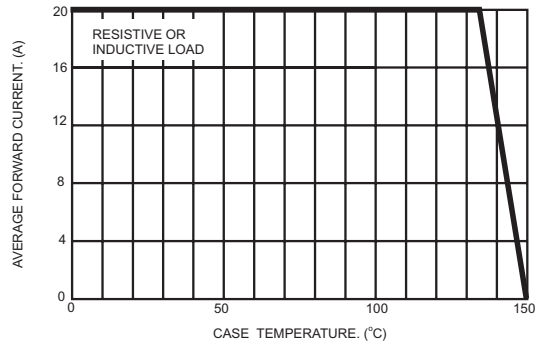


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

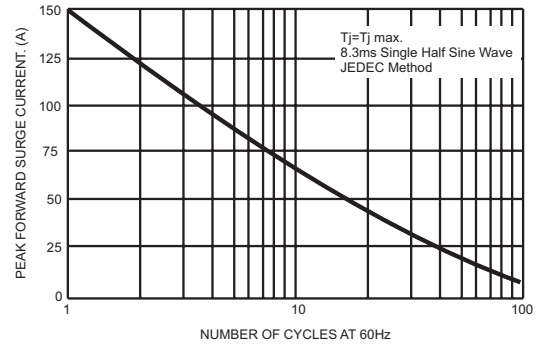


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

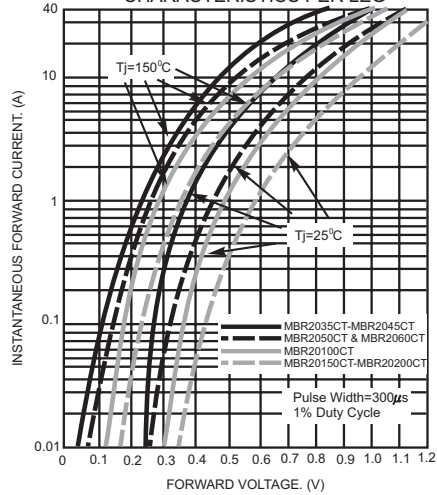


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER LEG

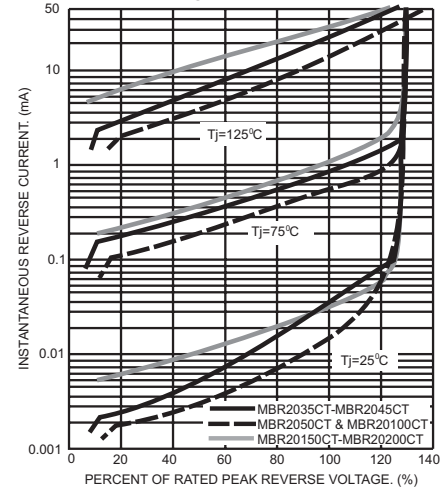


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

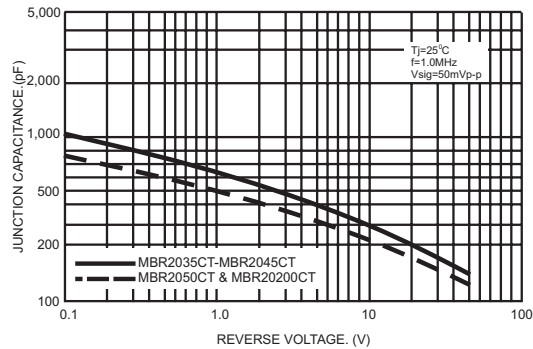
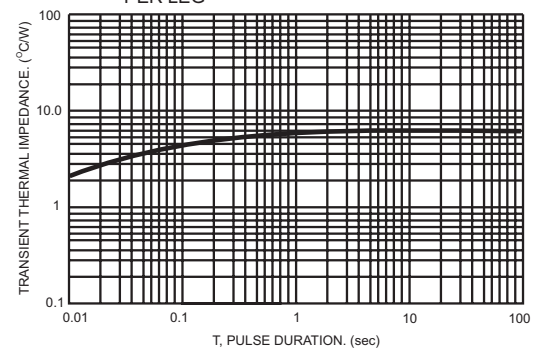


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG



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